

### Features

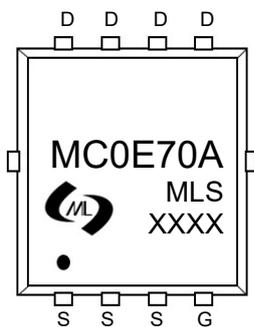
- High density cell design for ultra low  $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

### Product Summary

$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
40V	8m $\Omega$ @10V	70A
	10m $\Omega$ @4.5V	

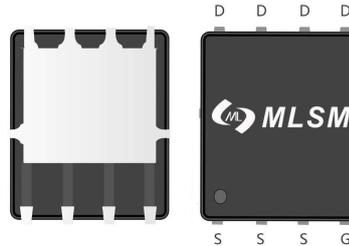
### Application

- Power switching application

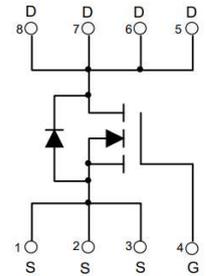


MC0E70A: Device code  
 XXXX : Code

Marking and pin assignment



PDFN5X6-8L view



Schematic diagram



Pb-Free



RoHS



Halogen-Free

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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### Common Ratings (TC=25°C Unless Otherwise Noted)

$V_{DS}$	Drain-Source Breakdown Voltage	40	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$T_J$	Maximum Junction Temperature	150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature Range	-50 to 155	$^{\circ}\text{C}$
$I_S$	Diode Continuous Forward Current	$T_c=25^{\circ}\text{C}$ 70	A

### Mounted on Large Heat Sink

$I_{DM}$	Pulse Drain Current Tested	$T_c=25^{\circ}\text{C}$ 270	A
$I_D$	Continuous Drain Current	$T_c=25^{\circ}\text{C}$ 70	A
$P_D$	Maximum Power Dissipation	$T_c=25^{\circ}\text{C}$ 85	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	108	$^{\circ}\text{C}/\text{W}$
$E_{AS}$	Single pulse avalanche energy <sup>Note1</sup>	81	mJ

### Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MC0E70A	PDFN5X6-8L	MC0E70A	5,000	10,000	70,000	13"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	40	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.5	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	--	6.5	8	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A	--	7.8	10	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1MHz	--	1800	--	pF
C <sub>OSS</sub>	Output Capacitance		--	210	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	170	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =20V, I <sub>D</sub> =20A, V <sub>GS</sub> =10V	--	45	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	6	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	10	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =30V, I <sub>D</sub> =20A, V <sub>GS</sub> =10V, R <sub>G</sub> =2.2Ω	--	6	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	20	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	53	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	33	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =20A	--	0.8	1.2	V

Note:

1: EAS Test condition: V<sub>DD</sub>=35V, V<sub>GS</sub>=10V, L=0.5mH, I<sub>D</sub>=18A, R<sub>G</sub>=25Ω, Starting T<sub>J</sub> = 25°C

Typical Operating Characteristics

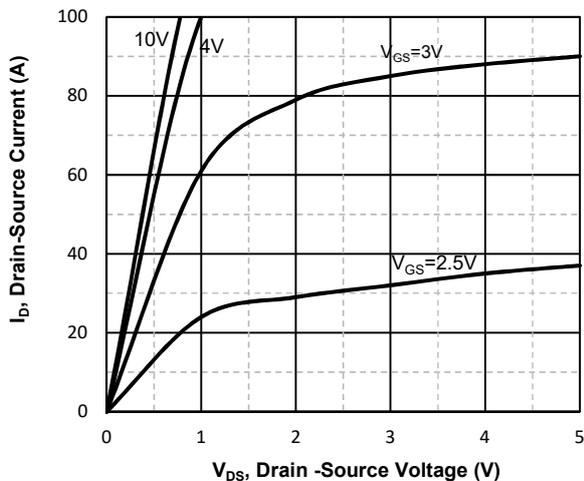


Fig1. Typical Output Characteristics

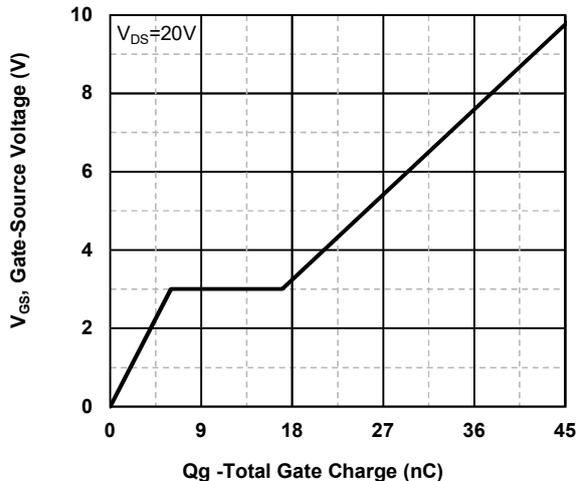


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

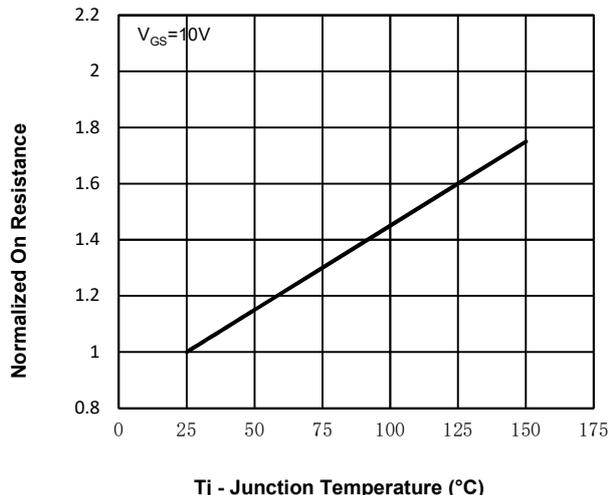


Fig3. Normalized On-Resistance Vs. Temperature

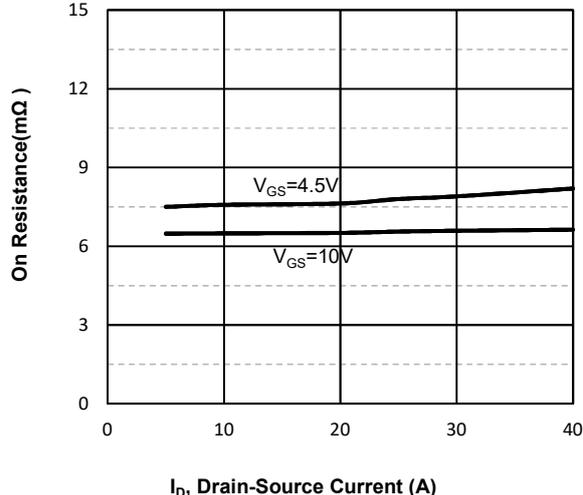


Fig4. On-Resistance Vs. Drain-Source Current

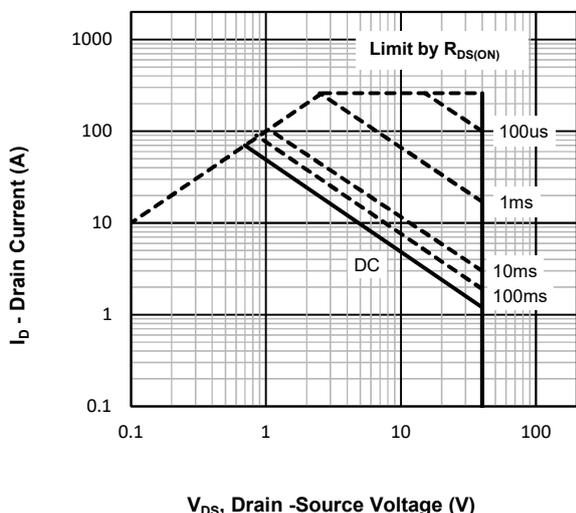


Fig5. Maximum Safe Operating Area

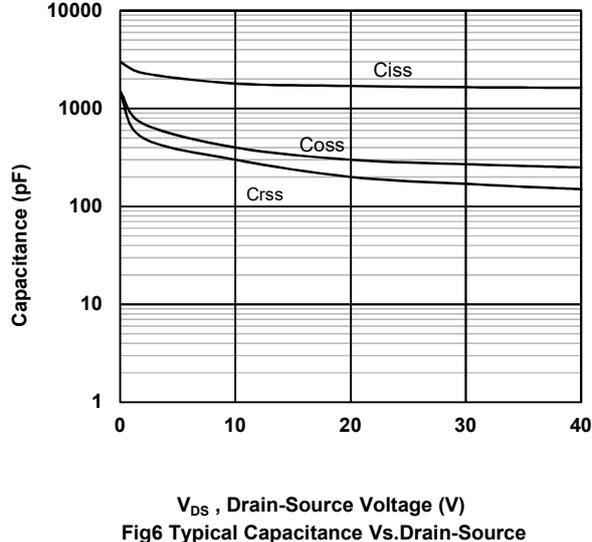
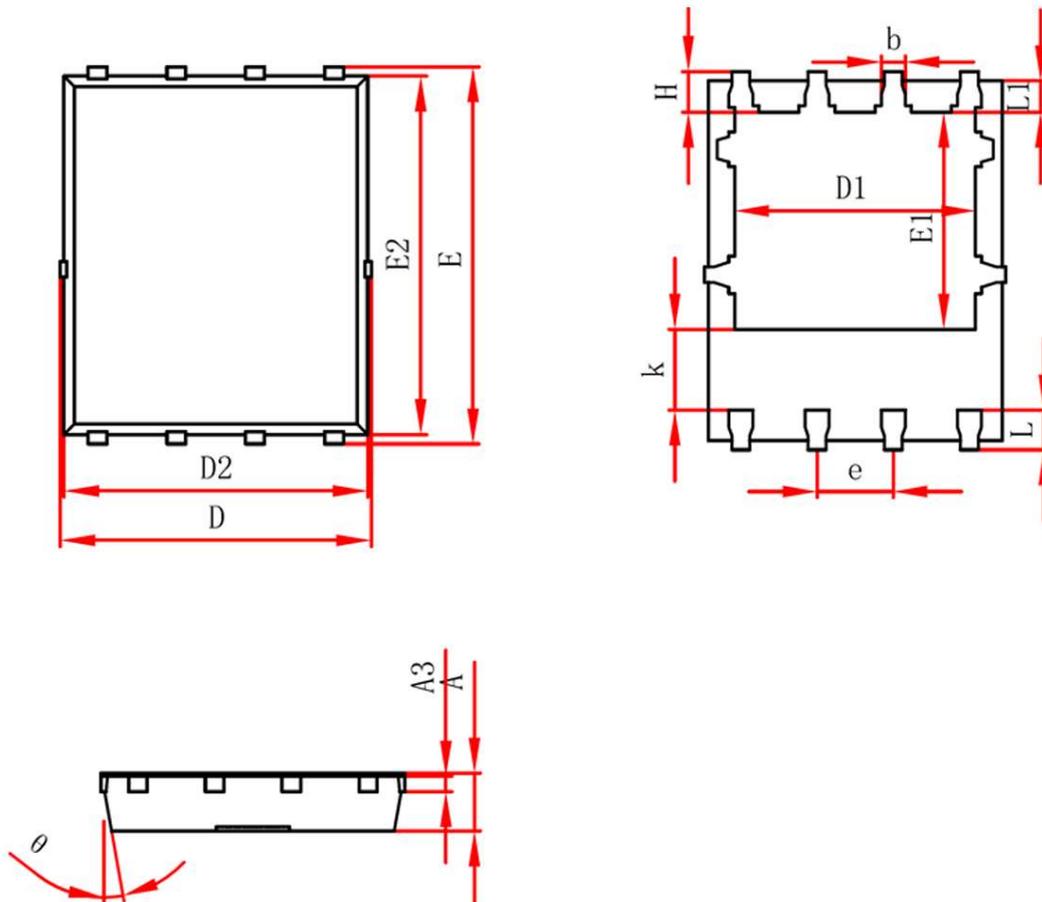


Fig6 Typical Capacitance Vs. Drain-Source

**PDFN5X6-8L Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	4.026	4.126	0.159	0.163
E1	3.510	3.610	0.139	0.143
D2	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
$\theta$	10°	12°	10°	12°